

# **PMDPB55XP** 20 V, dual P-channel Trench MOSFET Rev. 3 – 4 June 2012

Product data sheet

#### 1. **Product profile**

#### **1.1 General description**

Dual P-channel enhancement mode Field-Effect Transistor (FET) in a small and leadless ultra thin DFN2020-6 (SOT1118) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 1.2 Features and benefits

- Very fast switching
- Trench MOSFET technology
- 1.3 Applications
  - Charging switch for portable devices
  - DC/DC converters
  - Small brushless DC motor drive

- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Power management in battery-driven portables
- Hard disc and computing power management

#### 1.4 Quick reference data

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transi	stor						
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	<u>[1]</u>	-	-	-4.5	А
Static cha	racteristics (per transistor)						
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = -4.5 V; $I_D$ = -3.4 A; $T_j$ = 25 °C		-	55	70	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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## 2. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source TR1		54 50
2	G1	gate TR1	6 5 4	D1 D2
3	D2	drain TR2		
4	S2	source TR2	7 8	
5	G2	gate TR2		
6	D1	drain TR1	1 2 3	G1 S1 S2 G2
7	D1	drain TR1	Transparent top view	017aaa258
8	D2	drain TR2	SOT1118 (DFN2020-6)	

## 3. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMDPB55XP	DFN2020-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1118			

### 4. Marking

Table 4.   Marking codes	
Type number	Marking code
PMDPB55XP	1Z

#### 5. Limiting values

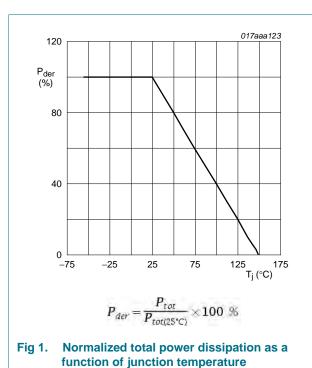
#### Table 5. Limiting values

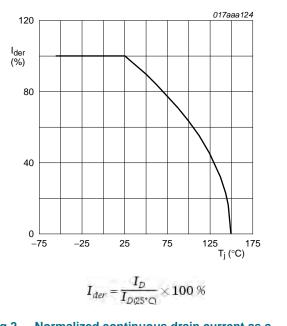
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per transist	tor					
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	<u>[1]</u>	-	-4.5	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	<u>[1]</u>	-	-3.4	А
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 100 °C	<u>[1]</u>	-	-2.2	А
I <sub>DM</sub>	peak drain current	$T_{amb} = 25 \text{ °C}$ ; single pulse; $t_p \le 10 \mu\text{s}$		-	-14	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	490	mW
			[1]	-	1170	mW
		T <sub>sp</sub> = 25 °C		-	8300	mW
Source-drai	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	<u>[1]</u>	-	-1.2	А
Per device						
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

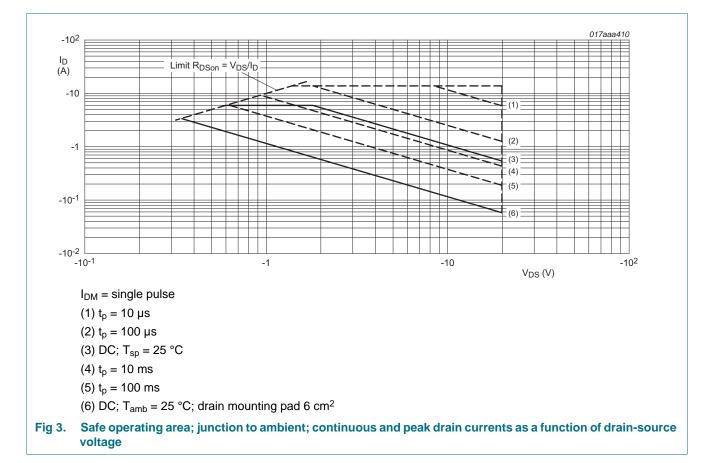






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#### 6. Thermal characteristics

Table 6. Thermal cha	aracteristics
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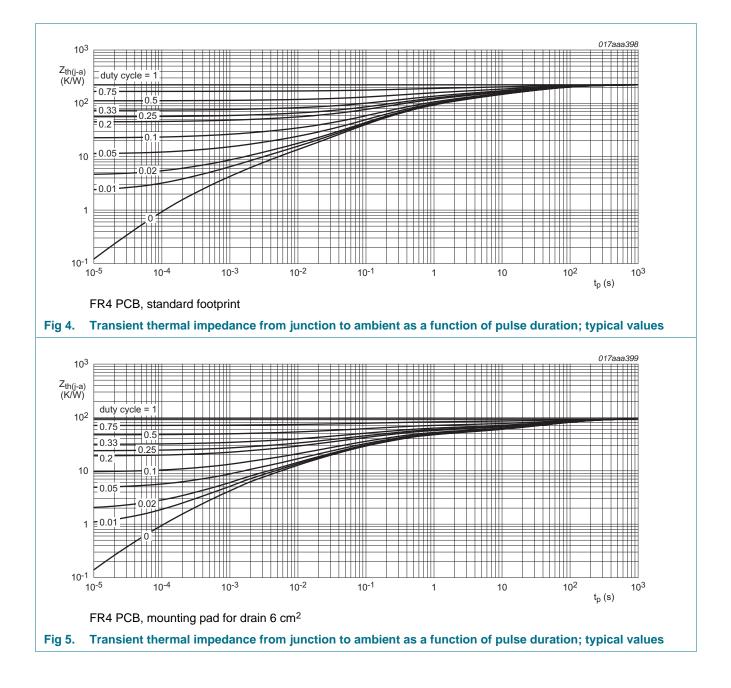
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
R <sub>th(j-a)</sub>	thermal resistance	in free air	<u>[1]</u>	-	223	256	K/W
	from junction to ambient	[2]	[2]	-	93	107	K/W
		in free air; t ≤ 5 s	[2]	-	55	63	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	in free air		-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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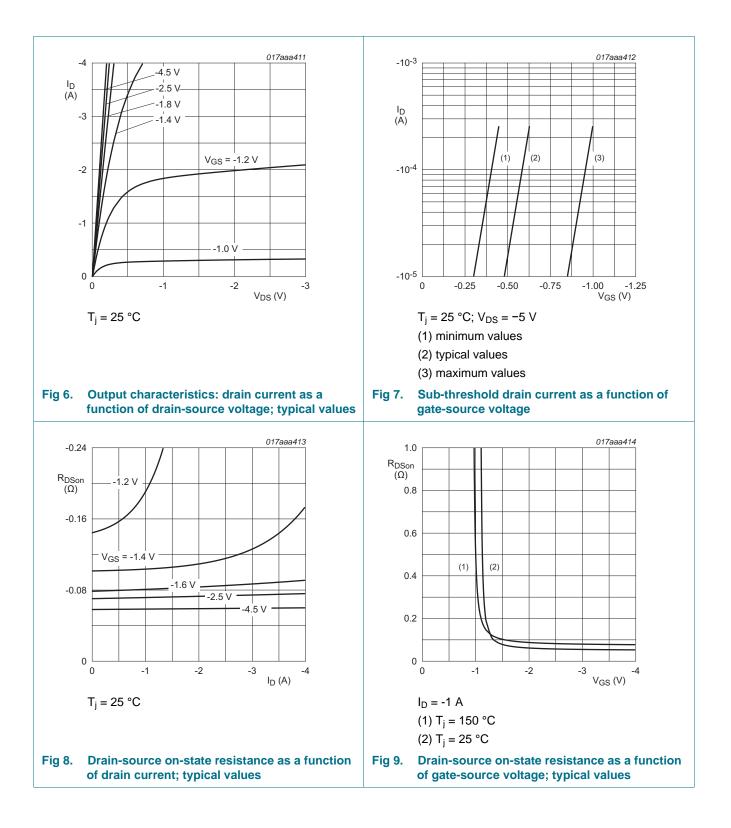
#### 20 V, dual P-channel Trench MOSFET

## 7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics (per transistor)					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D = -250 \ \mu A; V_{DS} = V_{GS}; T_j = 25 \ ^{\circ}C$	-0.47	-0.65	-0.9	V
I <sub>DSS</sub>	drain leakage current	$V_{DS} = -20 \text{ V}; \text{ V}_{GS} = 0 \text{ V}; \text{ T}_{j} = 25 \text{ °C}$	-	-	-1	μΑ
		$V_{DS} = -20 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 \text{ °C}$	-	-	-10	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
		$V_{GS} = -12 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	100	nA
$R_{DSon}$	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -3.4 A; T <sub>j</sub> = 25 °C	-	55	70	mΩ
	resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -3.4 A; T <sub>j</sub> = 150 °C	-	78	99	mΩ
		$V_{GS}$ = -2.5 V; $I_D$ = -1.6 A; $T_j$ = 25 °C	-	75	90	mΩ
		$V_{GS}$ = -1.8 V; I <sub>D</sub> = -1.5 A; T <sub>j</sub> = 25 °C	-	110	135	mΩ
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = -10 V; $I_D$ = -3.4 A; $T_j$ = 25 °C	-	15	-	S
Dynamic	characteristics (per transist	or)				
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; $I_{D}$ = -3.4 A; $V_{GS}$ = -5 V;	-	16.5	25	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1	-	nC
$Q_{GD}$	gate-drain charge		-	1.65	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	785	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	80	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	64	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; $I_{D}$ = -3.4 A; $V_{GS}$ = -5 V;	-	4	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 $ °C	-	14	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	135	-	ns
t <sub>f</sub>	fall time		-	68	-	ns
Source-d	rain diode (per transistor)					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1.2 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.8	-1.2	V

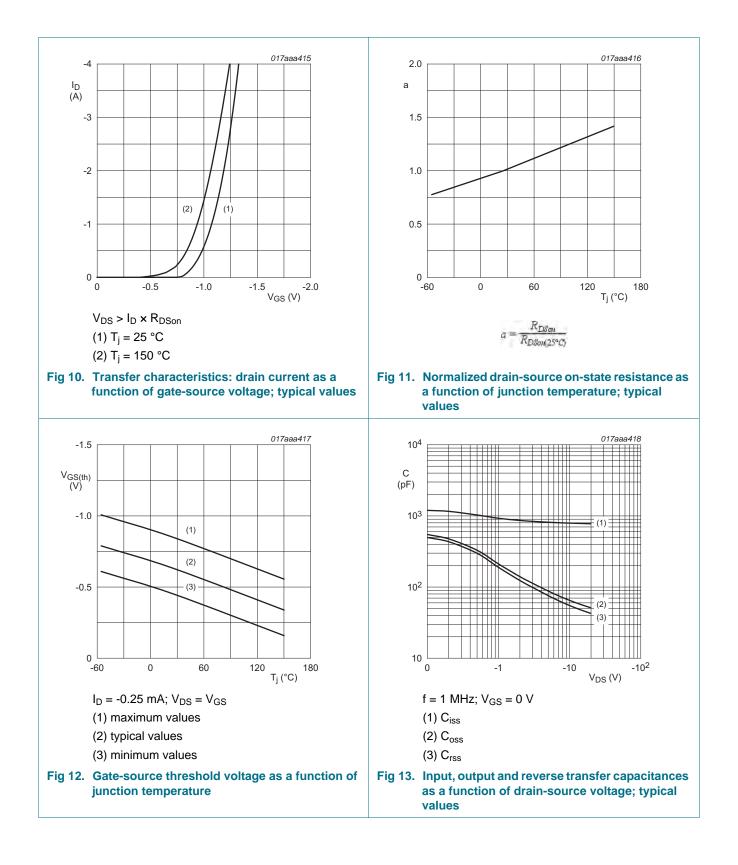
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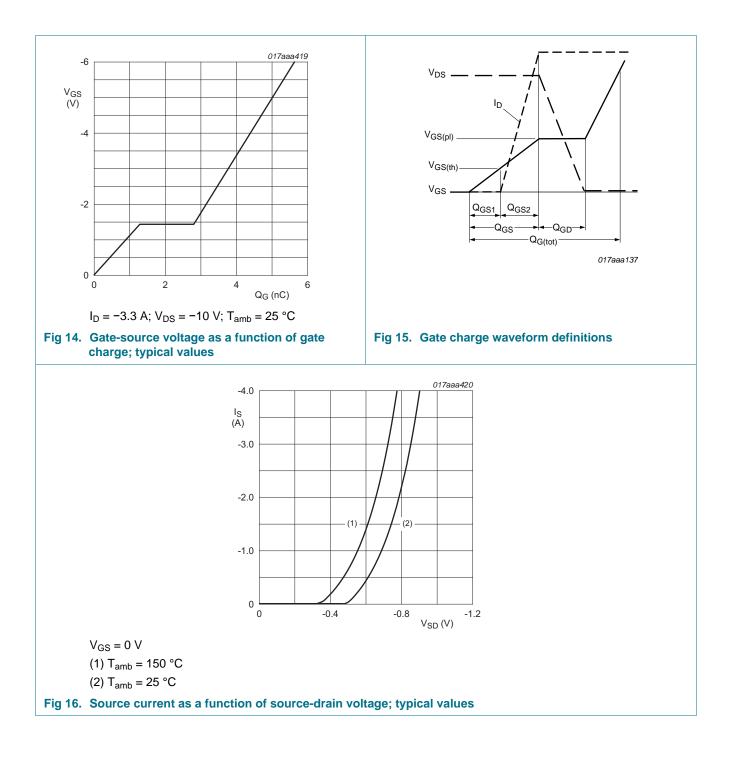
## PMDPB55XP

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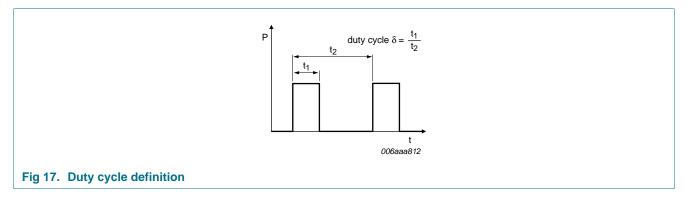
## PMDPB55XP

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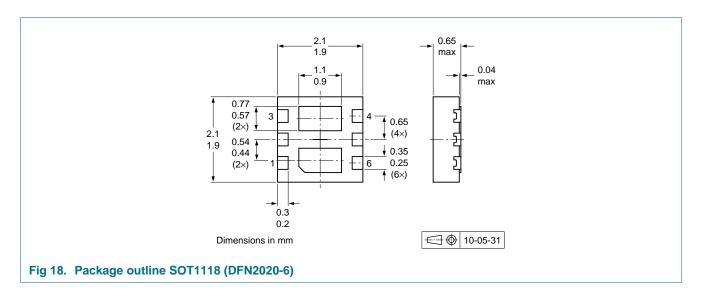


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#### 8. Test information

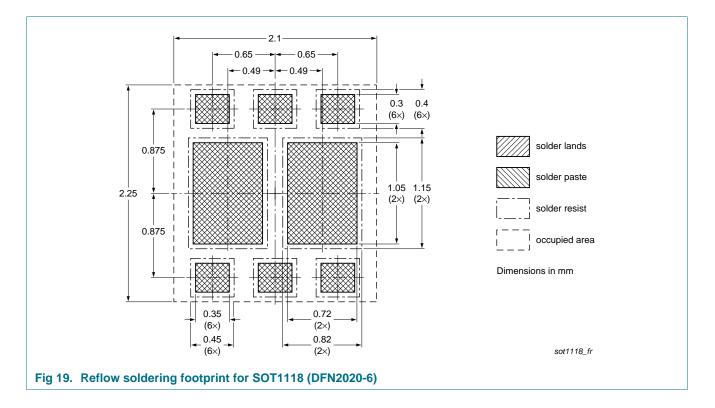


## 9. Package outline



#### 20 V, dual P-channel Trench MOSFET

## **10. Soldering**



#### 20 V, dual P-channel Trench MOSFET

## **11. Revision history**

Table 8.Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMDPB55XP v.3	20120604	Product data sheet	-	PMDPB55XP v.2
Modifications:	<ul> <li><u>Table 7.</u>: V<sub>GSt</sub></li> </ul>	h values updated		
PMDPB55XP v.2	20120502	Product data sheet	-	PMDPB55XP v.1
PMDPB55XP v.1	20120309	Product data sheet	-	-

#### **12. Legal information**

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Document status[1] [2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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**Product data sheet** 

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